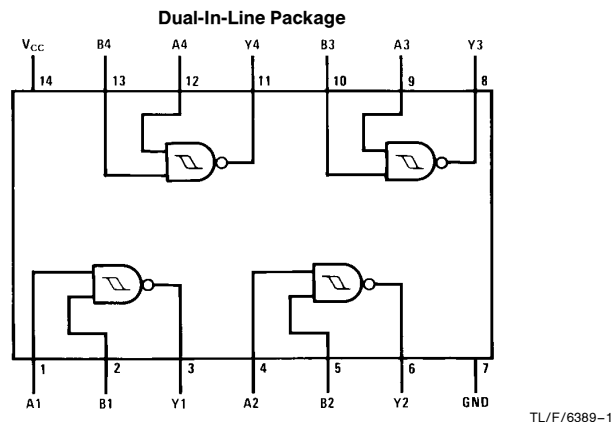


DM54LS132/DM74LS132 Quad 2-Input NAND Gates with Schmitt Trigger Inputs

General Description

This device contains four independent gates each of which performs the logic NAND function. Each input has hysteresis which increases the noise immunity and transforms a slowly changing input signal to a fast changing, jitter free output.

Connection Diagram



Order Number DM54LS132J, DM54LS132W, DM74LS132M or DM74LS132N
See NS Package Number J14A, M14A, N14A or W14B

Function Table

$$Y = \overline{AB}$$

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

H = High Logic Level

L = Low Logic Level

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS	−55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: The “Absolute Maximum Ratings” are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the “Electrical Characteristics” table are not guaranteed at the absolute maximum ratings. The “Recommended Operating Conditions” table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM54LS132			DM74LS132			Units
		Min	Nom	Max	Min	Nom	Max	
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{T+}	Positive-Going Input Threshold Voltage (Note 1)	1.4	1.6	1.9	1.4	1.6	1.9	V
V _{T−}	Negative-Going Input Threshold Voltage (Note 1)	0.5	0.8	1	0.5	0.8	1	V
HYS	Input Hysteresis (Note 1)	0.4	0.8		0.4	0.8		V
I _{OH}	High Level Output Current			−0.4			−0.4	mA
I _{OL}	Low Level Output Current			4			8	mA
T _A	Free Air Operating Temperature	−55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 2)	Max	Units
V _I	Input Clamp Voltage	V _{CC} = Min, I _I = −18 mA			−1.5	V
V _{OH}	High Level Output Voltage	V _{CC} = Min, I _{OH} = Max, V _I = V _{T−} Min	DM54 2.5 DM74 2.7	3.4 3.4		V
V _{OL}	Low Level Output Voltage	V _{CC} = Min, I _{OL} = Max, V _I = V _{T+} Max	DM54 DM74	0.25 0.35	0.4 0.5	V
		I _{OL} = 4 mA, V _{CC} = Min	DM74	0.25	0.4	
I _{T+}	Input Current at Positive-Going Threshold	V _{CC} = 5V, V _I = V _{T+}		−0.14		mA
I _{T−}	Input Current at Negative-Going Threshold	V _{CC} = 5V, V _I = V _{T−}		−0.18		mA
I _I	Input Current @ Max Input Voltage	V _{CC} = Max, V _I = 7V			0.1	mA
I _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.7V			20	μA
I _{IL}	Low Level Input Current	V _{CC} = Max, V _I = 0.4V			−0.4	mA
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 3)	DM54 DM74	−20 −20	−100 −100	mA
I _{CCH}	Supply Current with Outputs High	V _{CC} = Max		5.9	11	mA
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max		8.2	14	mA

Note 1: V_{CC} = 5V

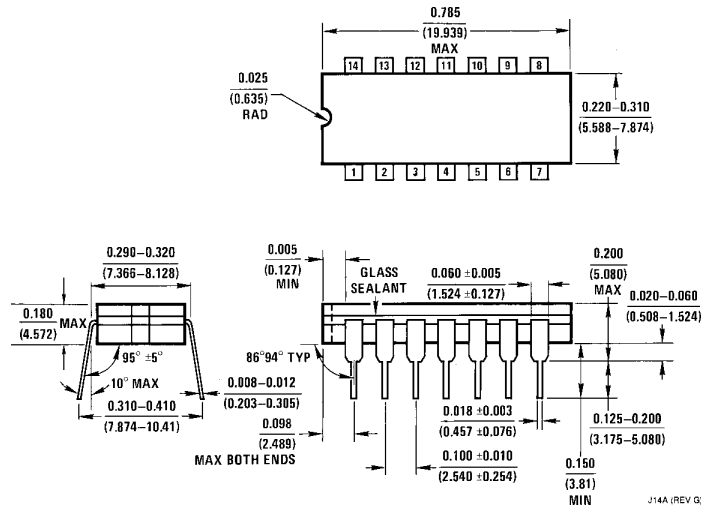
Note 2: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

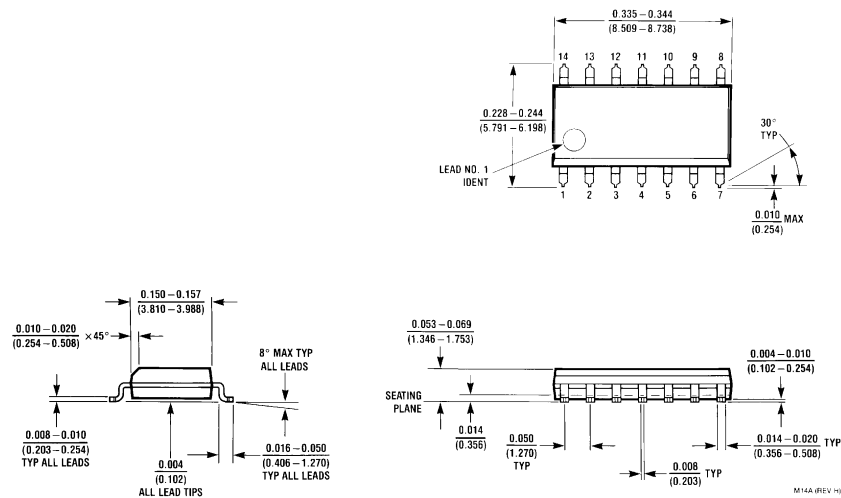
Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^\circ C$ (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	R _L = 2 kΩ				Units
		C _L = 15 pF		C _L = 50 pF		
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Time Low to High Level Output	5	22	8	25	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	5	22	10	33	ns

Physical Dimensions inches (millimeters)

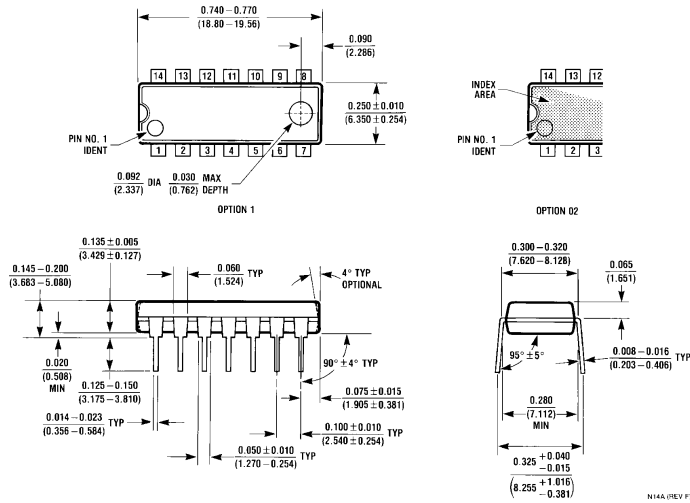


14-Lead Ceramic Dual-In-Line Package (J)
Order Number DM54LS132J
NS Package Number J14A

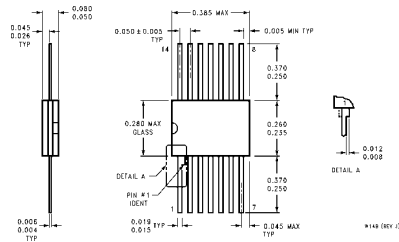


14-Lead Small Outline Molded Package (M)
Order Number DM74LS132M
NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Molded Dual-In-Line Package (N)
Order Number DM74LS132N
NS Package Number N14A



14-Lead Ceramic Flat Package (W)
Order Number DM54LS132W
NS Package Number W14B

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